REDACTED VERSION OF DOCUMENT SOUGHT TO BE SEALED 1 YAR R. CHAIKOVSKY (SB# 175421) yarchaikovsky@paulhastings.com 2 PHILIP OU (SB# 259896) philipou@paulhastings.com 3 ANDY LEGOLVAN (SB# 292520) andylegolvan@paulhastings.com 4 JOSEPH J. RUMPLER, II (SB# 296941) josephrumpler@paulhastings.com BERKELEY FIFE (SB# 325293) berkeleyfife@paulhastings.com 6 BORIS LUBARSKY (SB# 324896) borislubarsky@paulhastings.com PAUL HASTINGS LLP 1117 S. California Avenue 8 Palo Alto, California 94304-1106 Telephone: 1(650) 320-1800 9 Facsimile: 1(650) 320-1900 10 Attorneys for Plaintiff APPLIED MATERIALS, INC. 11 12 UNITED STATES DISTRICT COURT 13 NORTHERN DISTRICT OF CALIFORNIA 14 15 APPLIED MATERIALS, INC., CASE NO. 5:20-cv-05676-EJD DECLARATION OF Ryan Greater IN 16 Plaintiff. SUPPORT OF APPLIED MA 17 VS. INC.'S REPLY IN SUPPORT OF MOTION FOR PRELIMINARY DEMARAY LLC. 18 INJUNCTION 19 Defendant. REDACTED VERSION OF DOCUMENT SOUGHT TO BE SEALED 20 21 22 23 24 25 26 27 28



I, Ryan Greuter, hereby declare:

- I am an employee of Samsung Austin Semiconductor, LLC and have been since January of 2001. I am currently the Senior Director of CVD/Metals Engineering, and was previously the Senior Director of Etch Engineering.
- I submit this declaration in support of Applied Materials, Inc.'s ("Applied") Reply in support of its motion for preliminary injunction.
- Unless indicated otherwise, I have personal knowledge of the facts contained in this
 declaration and, if called upon to do so, I could and would testify competently to the matters set
 forth herein.
- 4. I understand that Demaray LLC ("Demaray") sued Samsung Austin Semiconductor, LLC as well as Samsung Electronics Co., Ltd., Samsung Electronics America, Inc., and Samsung Semiconductor, Inc. (collectively, the "Samsung Defendants") in Case No. 6:20-cv-00636-ADA in the United States District Court for the Western District of Texas ("Demaray-Samsung Litigation"), alleging infringement of U.S. Patent Nos. 7,544,276 and 7,381,657.
- 5. I understand that Demaray alleges that the Samsung Defendants infringe by using and/or configuring reactive magnetron sputtering reactors, including reactors in Applied's Endura product line, for the deposition of layers, which Demaray identifies as metal nitride layers such as TaN and/or TiN, in Samsung semiconductor products, including memory products such as Samsung's DDR4 SDRAM.
- 6. I also understand that Applied filed an action for declaratory judgment of non-infringement against Demaray in the United States District Court for the Northern District of California. I understand that, in that declaratory judgment action, Applied filed a motion for preliminary injunction to enjoin Demaray from proceeding with the Demaray-Samsung Litigation while the declaratory judgment action is pending.



1	7. Samsung Austin Semiconductor, LLC (SAS) owns and operates two semiconductor
2	fabrication facilities. SAS opened its original fab (FAB1) in 1997 and its second fab (FAB2) in
3	2007. Those facilities are located in Austin, Texas.
4	Those received in Flashii, Texas.
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20	I declare under penalty of perjury that the foregoing is true and correct.
21	DATED: October 9, 2020
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23	By: Ryn Great
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